
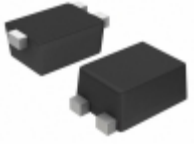







	<h2>NSBA114EDP6T5G</h2>
	<p>Hersteller-Teilenummer: NSBA114EDP6T5G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS 2PNP PREBIAS 0.338W SOT963</p> <p>Datenblätter:  NSBA114EDP6T5G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NSBA114EDP6T5G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS 2PNP PREBIAS 0.338W SOT963
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	6000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	338mW
Verpackung / Gehäuse	SOT-963
Supplier Device-Gehäuse	SOT-963
Transistor-Typ	2 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	35 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Tape & Reel (TR)

NSBA114EDP6T5G ist neu im Original, Suche NSBA114EDP6T5G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBA114EDP6T5G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBA114EDP6T5G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSBA113EF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS DUAL PNP</p>	 <p>NSBA114EDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>	 <p>NSBA114EDXV6T5G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>	 <p>NSBA113EDXV6T1 AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>
 <p>NSBA114EDXV6T5 AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>	 <p>NSB9435T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 0.72W SOT223</p>	 <p>NSBA113EDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.25W SOT563</p>	 <p>NSB9703 Desco COMMON POINT GND CORD 10MM 10'</p>

heiße Teile

Mehr

⚙️ A901S2800TPF	➡️ C1608X7R2A102M080AA	➡️ CNY17F-3X016	D DF10-48D12	➡️ DH-4S014
⚡ JM38510/00102BCB	⚙️ NSB1706DMW5T1G	D NSB4904DW1T1G	➡️ NSB8JT-E3/31	➡️ NSB9435T1
⚙️ NSB9435T1G	⚡ NSBA114EDXV6T1	⚙️ NSBA114YDXV6T1	➡️ NSBA123JDXV6T1	➡️ NSBA123JDXV6T1G
D NSBA123JDXV6T5G	⚙️ NSBA143TDXV6T1G	⚡ NSBA144EDP6T5G	⚙️ NSBC114EDXV6T1	➡️ NSBC114EDXV6T1G
➡️ NSBC114EPDXV6T1G	➡️ NSBC114EPDXV6T5	⚙️ NSBC114TDXV6T1	⚡ NSBC114YDP6T5G	➡️ NSBC114YDXV6T1
➡️ NSBC114YDXV6T1G	➡️ NSBC114YDXV6T5	D NSBC114YDPDXV6T1	⚙️ NSBC115EDXV6T1	⚡ NSBC123JDXV6T1
⚙️ NSBC123JPDV6T1	D NSBC123JPDV6T1G	➡️ NSBC124EPDXV6T1	➡️ NSBC124EPDXV6T5	➡️ NSBC124XPDXV6T1
⚡ NSBC143EDXV6T5	⚙️ NSBC143ZPDV6T1G	➡️ NSBC143ZPDV6T5	➡️ NSBC144EDXV6T1	➡️ NSBC144EDXV6T1G
⚙️ NSBC144EDXV6T5	⚡ NSBC144EDXV6T5G	⚙️ NSBC144EPDXV6T1	D NSBC144EPDXV6T1G	➡️ S-80940ANMP
➡️ SFHG60YQ101	⚙️ SIE01-06	⚡ SM16PHR134	⚙️ SRV05-4A.TCT	➡️ V375B48T300BG

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited